# TOSHIBA

## MIG15J805H

TENTATIVE

TOSHIBA INTEGRATED IGBT MODULE SILICON N CHANNEL IGBT

# MIG151805H

HIGH POWER SWITCHING APPLICATIONS

MOTOR CONTROL APPLICATIONS

- Integrates Inverter, Converter Power Circuits in One Package.
- Output (Inverter Stage)

: 3ø 15A/600V High Speed Type IGBT

 $V_{CE (sat)} = 2.80V (MAX.)$ 

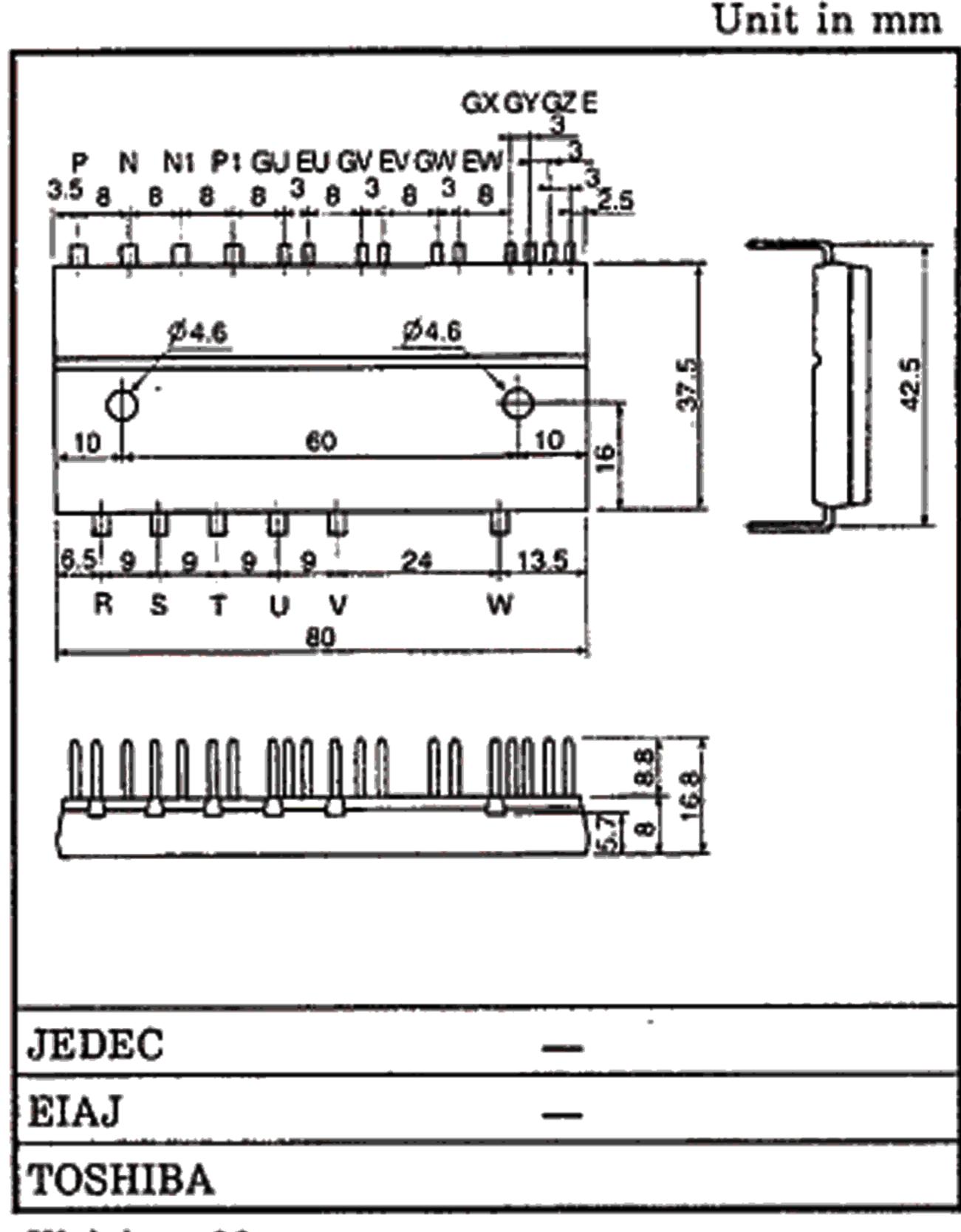
 $t_f = 0.30 \mu s \, (MAX.)$ 

 $t_{rr} = 0.15 \mu s \, (MAX.)$ 

- Input (Converter Stage)
  - : 3¢ 20A/800V Silicon Rectifier

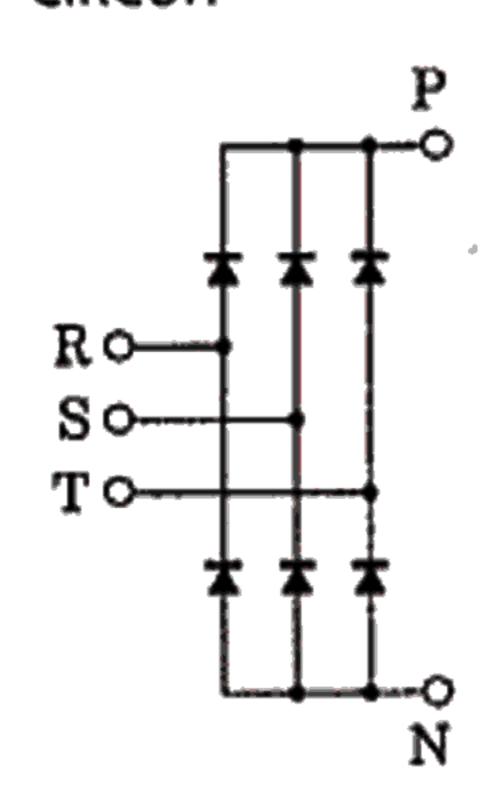
 $V_F = 1.30V (MAX.)$ 

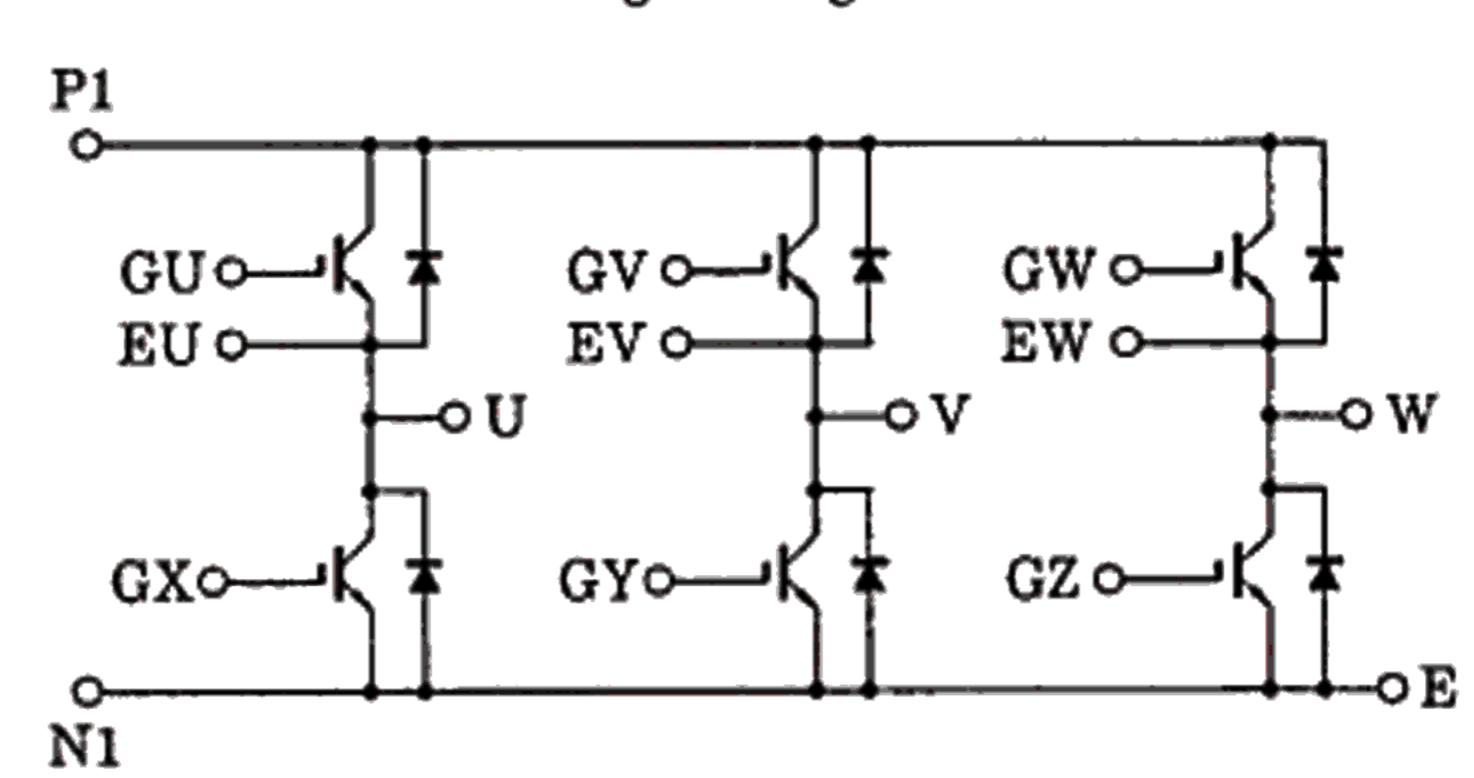
• The Electrodes are Isolated from Case.



Weight: 66g

#### **EQUIVALENT CIRCUIT**





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### MAXIMUM RATINGS (Ta = 25°C)

STAGE	CHARACTERISTIC		SYMBOL	RATING	UNIT
	Collector-Emitter Voltage		VCES	600	V
	Gate-Emitter Voltage		VCES     600       VGES     ±20       C     IC     15       as     ICP     30       C     IF     15       as     IFM     30       PC     55       VRRM     800       at     IO     20       IFSM     250       Tj     150       Tstg     -40~125       VIsol     (AC 1 minute)	V	
	Callagian Carmont	DC	IC	600 V  ±20 V  15 A  30 A  15 A  30 A  55 W  800 V  20 A  250 A  150 °C  -40~125 °C	
Turrantan	Collector Current	1ms	ICP	30	Α
Inverter	Easterna Comment	1ms I <sub>FM</sub> 30	A		
	Forward Current	1ms	IFM	30	Α
	Collector Power Dissipation (Tc=25°C)		PC	55	W
	Repetitive Peak Reverse Voltage		VRRM	800	V
Contraston	Average Output Rectified (	Current	IO	20	Α
Converter	Peak One Cycle Surge Forward Current (50Hz, Non-Repetitive)		IFSM	250	Α
	Junction Temperature		Tj	150	°C
	Storage Temperature Rang	age Temperature Range		-40~125	°C
Module	Isolation Voltage		37-		V
	Screw Torque		T <sub>stg</sub> 150  T <sub>stg</sub> -40~125  V <sub>Isol</sub> 2500  (AC 1 minute)	N∙m	

# ELECTRICAL CHARACTERISTICS (Ta = 25°C)

#### a. Inverter stage

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CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Gate Leakage Current		IGES	$V_{GE} = \pm 20V$ , $V_{CE} = 0$			±500	nA
Collector Cut-off Current		ICES	$V_{CE}=600V$ , $V_{GE}=0$	_		1.0	mA
Gate-Emitter Cut-off Voltage		VGE (off)	$I_C=1.5mA$ , $V_{CE}=5V$	5.0		8.0	V
Collector-Emitter Saturation Voltage		VCE (sat)	IC=15A, VGE=15V	_	2.10	2.80	v
Input Capaci	nput Capacitance		$V_{CE}=10V$ , $V_{GE}=0$ , $f=1MHz$	_			pF
Switching Time	Rise Time	tr	$V_{CC}=300V$ $I_{C}=15A$ $V_{GE}=\pm15V$ $R_{G}=82\Omega$ (Note 1)		0.07	0.15	μs
	Turn-on Time	ton			0.15	0.30	
	Fall Time	tf		_	0.15	0.30	
	Turn-off Time	toff		_	0.50	1.00	
Forward Volt	Forward Voltage		$I_F=15A$ , $V_{GE}=0$		2.30	2.80	V
Reverse Recovery Time		trr	$I_F=15A$ , $V_{GE}=-10V$ $di/dt=50A/\mu s$	_	0.08	0.15	μs
Thermal Resistance		ъ	Transistor			2.27	°C/W
		Rth (j-c)	Diode			3.09	) U/W

#### b. Converter stage

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Repetitive Peak Reverse Current	IRRM	VRRM=800V	_	_	50	μΑ
Peak Forward Voltage	$v_{FM}$	$I_{\text{FM}} = 20A$	_	1.05	1.30	V
Peak One Cycle Surge Forward Current	IFSM	50Hz sine-half-wave	250	_	_	A
Thermal Resistance	Rth (j-c)	_			2.80	°C/W

(Note 1) Switching Time Test Circuit & Timing Chart

